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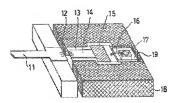
: 18-10-91 APPLICATION DATE : 03297969 APPLICATION NUMBER

APPLICANT: NEC CORP:

INT.CL. : H01S 3/18

INVENTOR: TOMITA KEISAKU:

TITLE : SEMICONDUCTOR LASER DEVICE



ABSTRACT: PURPOSE: To increase the input current for semiconductor laser used for a high-speed optical telecommunication system in order to realize a long-distance transmission.

> CONSTITUTION: The characteristic impedance between an input terminal 11 and a strip line 14 is matched to the output impedance of a drive circuit (for example, 50Ω), however, the impedance is set lower than the output impedance of the drive circuit when a thin-film resistor 14 and semiconductor laser 17 are viewed from the strip-line side (for example, when the input impedance of the semiconductor is 5Ω , the resistance value of the thin-film resistor 14 is set to 20Ω.

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